

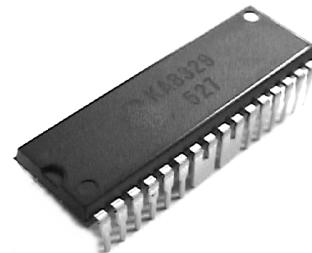
### 3-PHASE CAPSTAN MOTOR DRIVER

The KA8329B is a monolithic integrated circuit, and it is suitable for 3-phase capstan motor driver of VCR system.

### FEATURES

- 3-phase, full-wave, linear BLDC motor driver with 3 hall sensors
- Built-in TSD (Thermal shutdown) circuit
- Built-in torque ripple control circuit
- Built-in output current limiter
- Motor speed control
- High output current
- Built-in FG amplifier with sinusoidal waveforms
- Built-in hall amplifier
- Built-in CW and CCW circuit

32-SDIPH-400



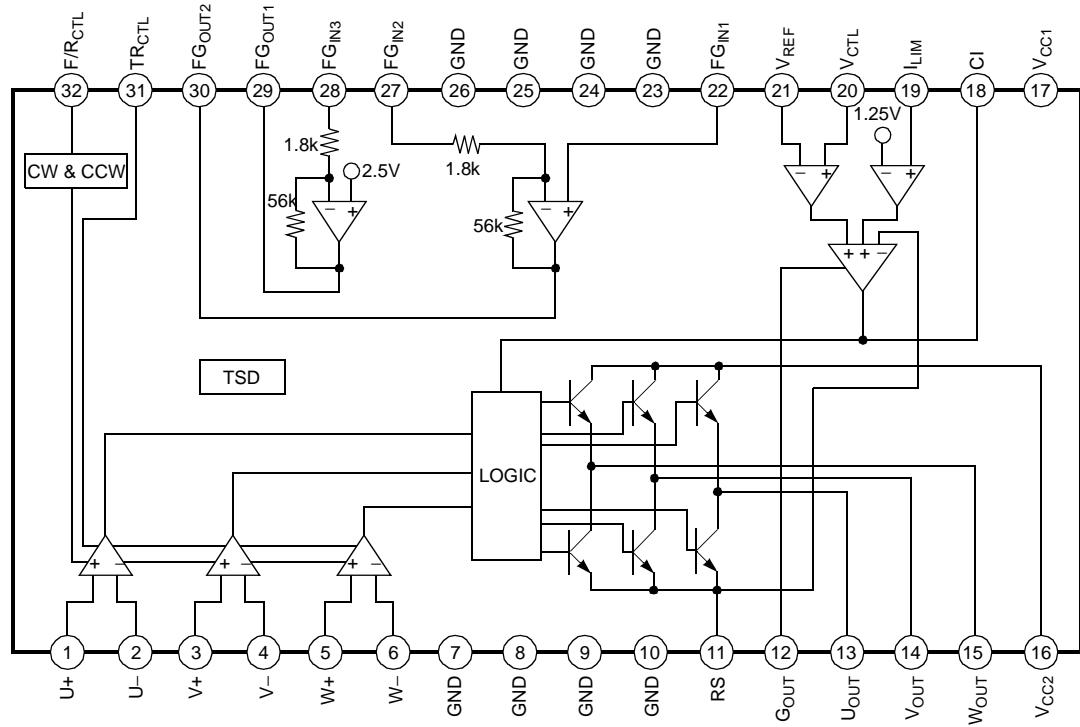
### ORDERING INFORMATION

Device	Package	Operating Temperature
KA8329B	32-SDIPH-400	-25°C ~ +75°C

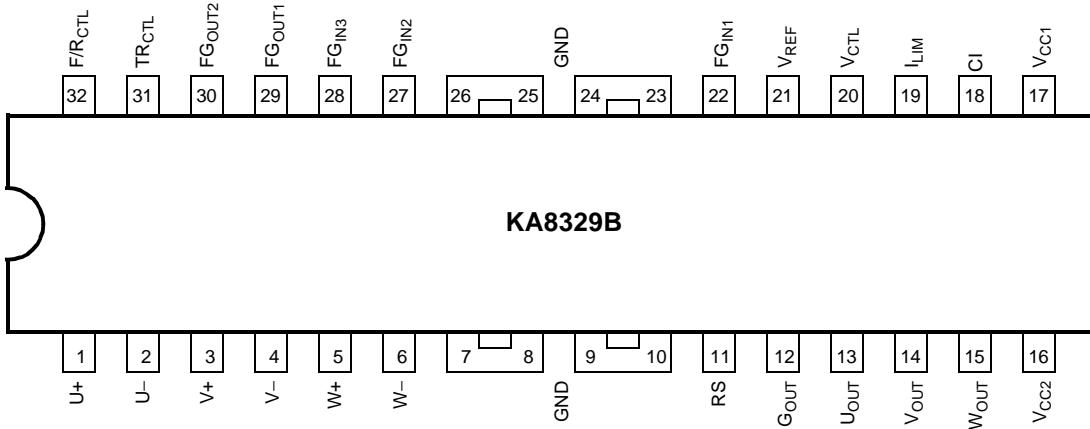
### TARGET APPLICATION

- VCR capstan motors

### BLOCK DIAGRAM



## PIN CONFIGURATIONS



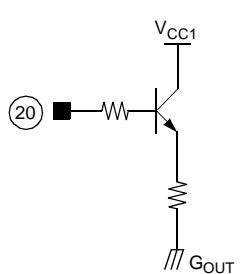
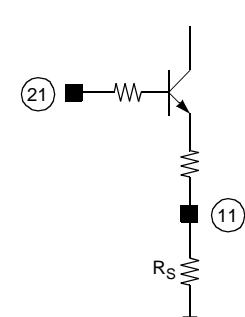
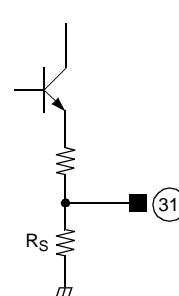
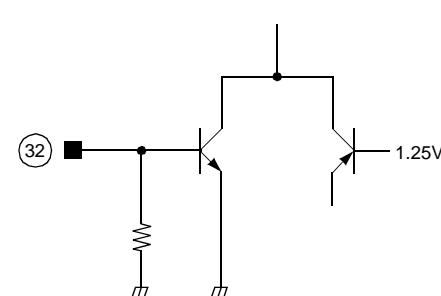
## PIN DESCRIPTION

Pin No.	Symbol	I/O	Description	Pin No.	Symbol	I/O	Description
1	U <sup>+</sup>	I	U+ hall signal input	17	V <sub>CC1</sub>	-	Supply voltage
2	U <sup>-</sup>	I	U- hall signal input	18	C <sub>I</sub>	-	Phase stabilization
3	V <sup>+</sup>	I	V+ hall signal input	19	I <sub>LIM</sub>	I	Current limitation
4	V <sup>-</sup>	I	V- hall signal input	20	V <sub>CTL</sub>	I	Voltage control
5	W <sup>+</sup>	I	W+ hall signal input	21	V <sub>REF</sub>	I	Voltage control reference
6	W <sup>-</sup>	I	W- hall signal input	22	F <sub>G</sub> <sub>IN1</sub>	I	FG amp1 input1
7	GND	-	Ground (Signal)	23	GND	-	Ground (Signal)
8	GND	-	Ground (Signal)	24	GND	-	Ground (Signal)
9	GND	-	Ground (Signal)	25	GND	-	Ground (Signal)
10	GND	-	Ground (Signal)	26	GND	-	Ground (Signal)
11	RS	O	Output current detection	27	F <sub>G</sub> <sub>IN2</sub>	I	FG amp1 input2
12	G <sub>OUT</sub>	-	Ground (Power)	28	F <sub>G</sub> <sub>IN3</sub>	I	FG amp2 input1
13	U <sub>OUT</sub>	O	U-phase output	29	F <sub>G</sub> <sub>OUT1</sub>	O	FG amp2 output
14	V <sub>OUT</sub>	O	V-phase output	30	F <sub>G</sub> <sub>OUT2</sub>	O	FG amp1 output
15	W <sub>OUT</sub>	O	W-phase output	31	T <sub>R</sub> <sub>CTL</sub>	I	Torque ripple control
16	V <sub>CC2</sub>	-	Supply voltage (Power)	32	F/R <sub>CTL</sub>	I	Forward & reverse control

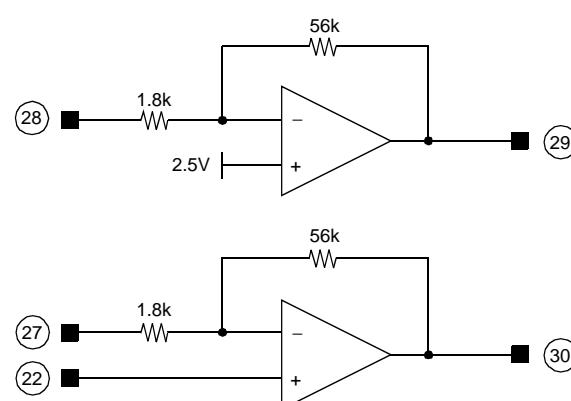
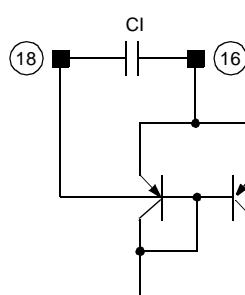
## INTERNAL CIRCUIT

Description	Pin No.	Internal circuit
Hall input	1, 2, 3 4, 5, 6	<p>The diagram shows two Hall effect sensors (1, 3, 5) and (2, 4, 6) connected in series. Each sensor has a resistor in series with its output. The outputs of the two sensors are connected to the bases of two transistors. The collectors of these transistors are connected to a common ground line. The emitters of the transistors are connected to a logic inverter, which provides the output.</p>
Output & Current detection	13, 14, 15, 12	<p>The diagram shows a driver stage consisting of four transistors. The outputs of this stage are connected to three output pins: U<sub>OUT</sub> (pin 13), V<sub>OUT</sub> (pin 14), and W<sub>OUT</sub> (pin 15). A resistor R<sub>S</sub> (0.5Ω) is connected between pin 11 and ground. Pin 12 is connected to the collector of a transistor, which is also connected to ground through a resistor.</p>
Speed control (Current limitation)	19	<p>The diagram shows a current limit stage consisting of a single transistor. The base is connected to pin 19, which is connected to a resistor. The collector of the transistor is connected to ground through a resistor.</p>

## INTERNAL CIRCUIT (Continued)

Description	Pin No.	Internal circuit
Speed control (Voltage control)	20	
Voltage control reference	21	
Torque ripple control	31	
Forward & Reverse control	32	

## INTERNAL CIRCUIT (Continued)

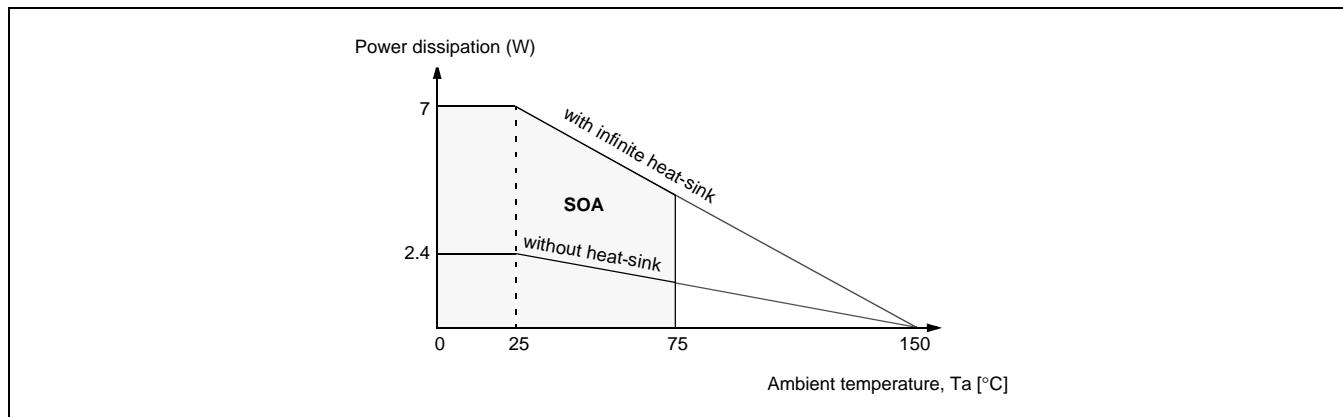
Description	Pin No.	Internal circuit
FG AMP.	28, 29 22, 27, 30	
Phase stabilization	16, 18	

**ABSOLUTE MAXIMUM RATING (Ta=25°C)**

Characteristics	Symbol	Value	Unit	Remark
Supply voltage (Signal)	V <sub>CC1max</sub>	7	V	–
Supply voltage (Power)	V <sub>CC2max</sub>	28	V	–
Output current	I <sub>Omax</sub>	1.5 <sup>note1</sup>	A / Phase	–
Power dissipation	P <sub>d</sub>	2.4 <sup>note2</sup>	W	No heat sink
Thermal resistance	R <sub>T</sub>	60.2	mW / °C	No heat sink
Junction temperature	T <sub>J</sub>	150	°C	–
Operating temperature	T <sub>OPR</sub>	-25 ~ +75	°C	–
Storage temperature	T <sub>STG</sub>	-40 ~ +125	°C	–

**NOTES:**

1. Duty 1/100, pulse width 500μs
2. 1) When mounted on glass epoxy PCB (76.2 × 114 × 1.57mm)  
2) Power dissipation reduces 19.2mW / °C for using above Ta=25°C. (Without heat-sink)  
3) Do not exceed Pd and SOA.

**PD GRAPH****RECOMMENDED OPERATING CONDITIONS (Ta=25°C)**

Characteristics	Symbol	Value	Unit
Operating supply voltage (Signal)	V <sub>CC1</sub>	4.5 ~ 5.5	V
Operating supply voltage (Power)	V <sub>CC2</sub>	8 ~ 27	V

## ELECTRICAL CHARACTERISTICS

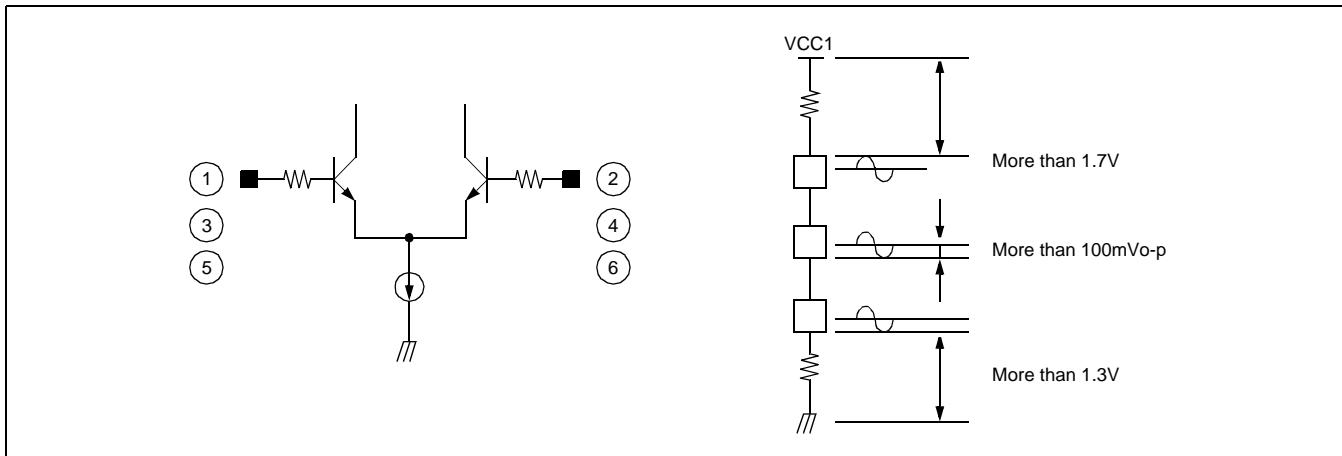
(Ta=25°C, V<sub>CC1</sub>=5V, V<sub>CC2</sub>=16V, R<sub>S</sub>=0.5Ω, unless otherwise specified)

Characteristic	Symbol	Pin No.	Test conditions	Min.	Typ.	max.	Unit
Quiescent input current	I <sub>CC1</sub>	17	VF/R=0V or 5V	5	8.5	12	mA
Hall amp. input voltage range	V <sub>INS</sub>	1 ~ 6	mVo-p	100	—	—	mV
Power TR stauration voltage (Outflow current)	V <sub>SAT1</sub>	16– 13, 14, 15	V <sub>CC2</sub> =13V, I <sub>OUT</sub> =0.8A/Phase	—	1.8	2.0	V
Power TR saturation voltage (Inflow current)	V <sub>SAT2</sub>	11– 13, 14, 15	V <sub>CC2</sub> =13V, I <sub>OUT</sub> =0.8A/Phase	—	1.8	2.0	V
I <sub>LIM</sub> input voltage range	V <sub>LIM</sub>	19	—	0	—	V <sub>CC1</sub>	V
I <sub>LIM</sub> input current	I <sub>19</sub>	19	V <sub>CTL</sub> =3.5V, V <sub>LIM</sub> =3V	—	350	2000	nA
I <sub>LIM</sub> current limit level	GML	19– 13, 14, 15	V <sub>CTL</sub> =3.5V, V <sub>LIM</sub> =Adjustable	0.61	0.67	0.73	A/V
I <sub>LIM</sub> quiescent output current	I <sub>O1</sub>	19	V <sub>LIM</sub> =0V	—	1.5	5.0	mA
I <sub>LIM</sub> limit offset voltage	V <sub>O1</sub>	19	V <sub>REF</sub> =2.5V	1.17	1.25	1.33	V
V <sub>CTL</sub> input voltage range	V <sub>CTL</sub>	20	—	0	—	V <sub>CC1</sub>	V
V <sub>CTL</sub> input current	I <sub>20</sub>	20	V <sub>CTL</sub> =3V, V <sub>LIM</sub> =5V	—	350	2000	nA
V <sub>CTL</sub> control gain	GM	20– 13, 14, 15	V <sub>CTL</sub> =3.5V, V <sub>LIM</sub> =Adjustable	0.9	1.0	1.1	A/V
V <sub>CTL</sub> quiescent output current	I <sub>O2</sub>	20	V <sub>CTL</sub> =0V	—	1.5	5.0	mA
V <sub>CTL</sub> input offset voltage	V <sub>O2</sub>	20	V <sub>CTL</sub> =Adjustable	-50	0	50	mV
Forward rotation mode	V <sub>F</sub>	32	—	1.0	1.3	1.6	V
Reverse rotation mode	V <sub>R</sub>	32	—	0	—	0.8	—
V <sub>REF</sub> input voltage range	V <sub>REF</sub>	21	—	2.0	—	V <sub>CC1</sub> – 2.0	V
FG <sub>AMP</sub> internal reference voltage	V <sub>28</sub>	28	—	2.2	2.5 —	2.8	V V
FG <sub>AMP</sub> input voltage range	FG <sub>IN</sub>	27, 28	Pin28=10kHz, 60mVp-p	1	—	4	—
FG <sub>AMP1</sub> gain	FG <sub>AV1</sub>	28, 29	Sinusoidal waveforms Pin27=10kHz, 60mVp-p	28	31	34	Times
FG <sub>AMP2</sub> gain	FG <sub>AV2</sub>	27 ~ 30	Sinusoidal waveforms Pin22=2.5V	28	31	34	Times

## APPLICATION INFORMATION

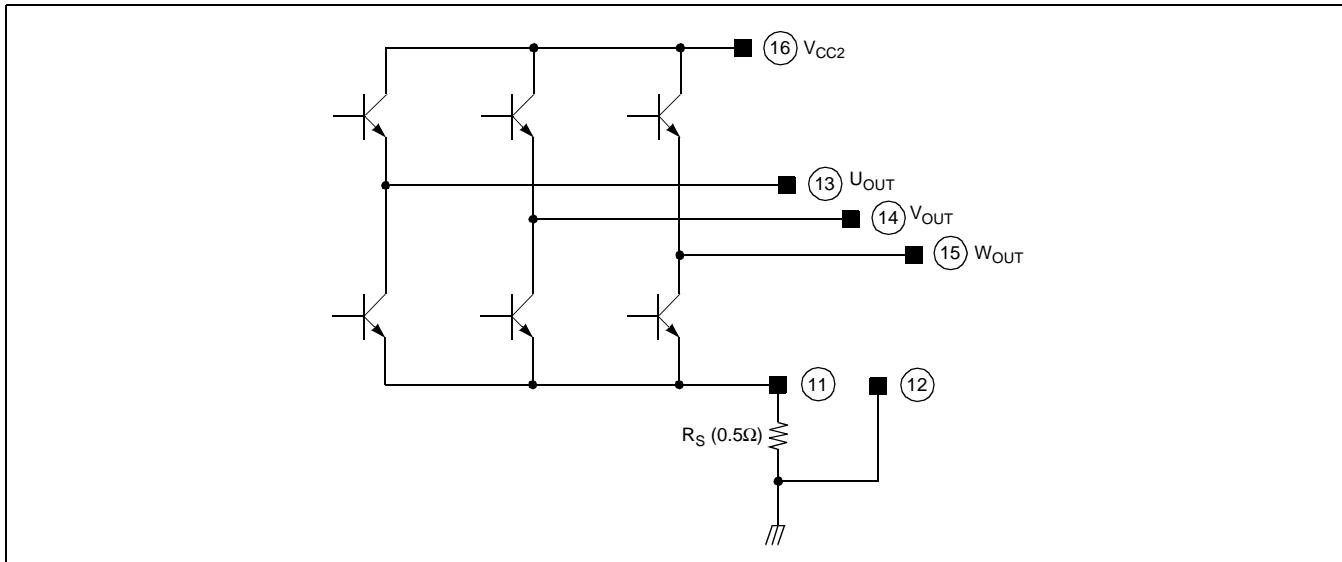
### 1. HALL INPUT

The input signal of the hall sensor requires more amplitude than 100mVo-p. and the operating voltage level of the hall sensor is from 1.2V ~ V<sub>CC1</sub>-0.8V.



### 2. OUTPUT CURRENT DETECTION

Pin 11 is usually connected with R<sub>S</sub> (Approx. 0.5Ω), and the motor current is converted to a voltage by the R<sub>S</sub> and provided to a feedback amplifier. Pin 12 is connected to the circuit with the ground side or R<sub>S</sub>.

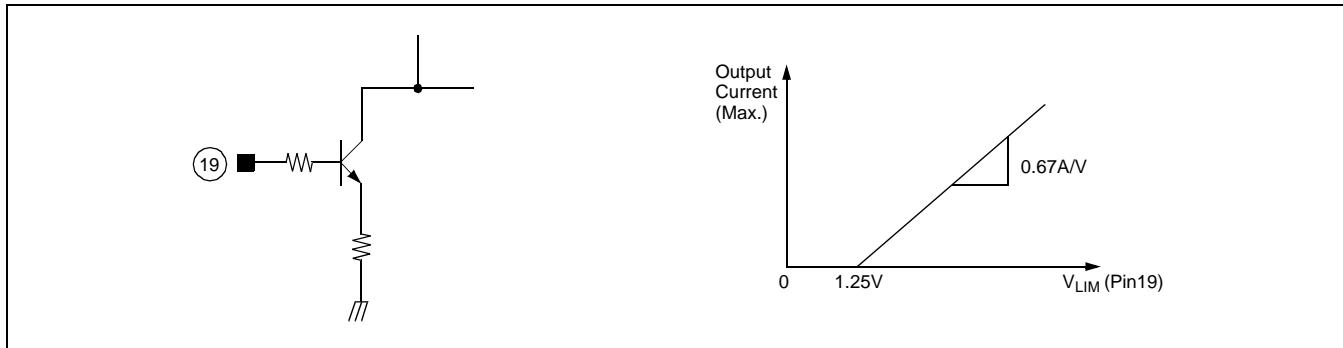


### 3. MOTOR SPEED CONTROL (INPUT CURRENT LIMITATION)

The maximum output current is limited by pin 19 voltage as follows. So a motor speed is controlled by the output current. In case of no-use, it is to be short-circuit with  $V_{CC1}$ .

$$GML = \Delta I_O / \Delta V_{LIM} = (I_{O2} - I_{O1}) / (V_{LIM2} - V_{LIM1}), \text{ where } V_{LIM1} = 1.45V \rightarrow \text{Output current}=I_{O1}$$

$$V_{LIM2} = 1.55V \rightarrow \text{Output current}=I_{O2}$$

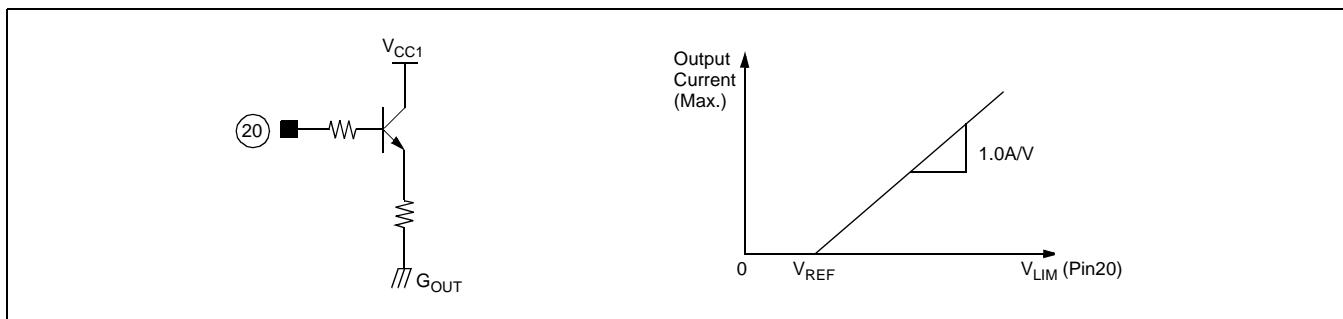


### 4. MOTOR SPEED CONTROL (INPUT VOLTAGE CONTROL)

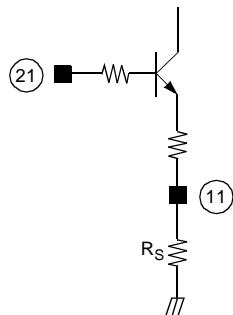
The control of motor speed is possible on the conditions of  $V_{CTL}$  (Pin20)  $\geq V_{REF}$ .  
The control gain is approx. 1.0A/V as follows.

$$GML = \Delta I_O / \Delta V_{CTL} = (I_{O2} - I_{O1}) / (V_{CTL2} - V_{CTL1}), \text{ where } V_{REF} = 2.5V, V_{CTL1} = 2.6V \rightarrow \text{Output current}=I_{O1}$$

$$V_{REF} = 2.5V, V_{CTL2} = 2.7V \rightarrow \text{Output current}=I_{O2}$$

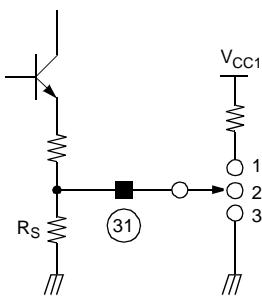


## 5. VOLTAGE CONTROL REFERENCE



The input voltage range is  $2V \leq V_{REF} \leq (V_{CC1} - 2V)$ .

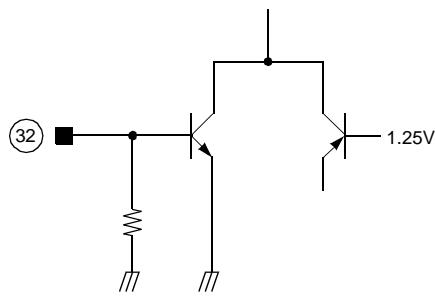
## 6. TORQUE RIPPLE CONTROL



The motor torque ripple is controlled by Pin 31 voltage as follows.

1. GND
2. Normal Mode
3. Control Mode

## 7. FORWARD & REVERSE ROTATION CONTROL

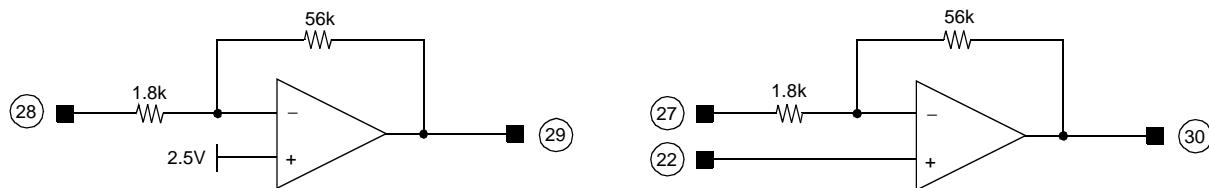


Forward mode: Pin 32  $\geq$  1.8V

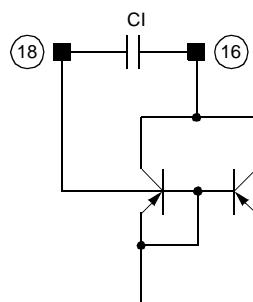
Reverse mode: Pin 32  $\leq$  0.8V

## 8. FG AMP

These amplifiers are the inversion type. One amplifier is built in both the reference voltage (Approx. 2.5V) and the gain setting resistors. The voltage gain is approx. 31 times.

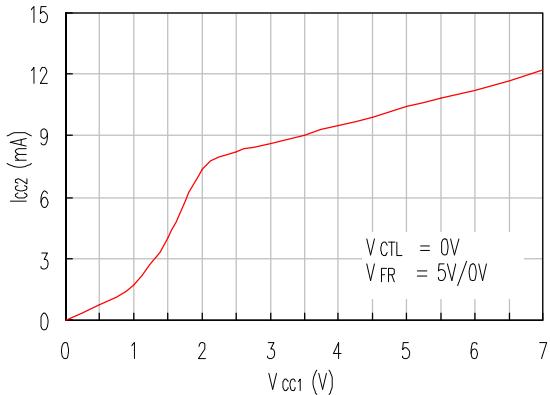
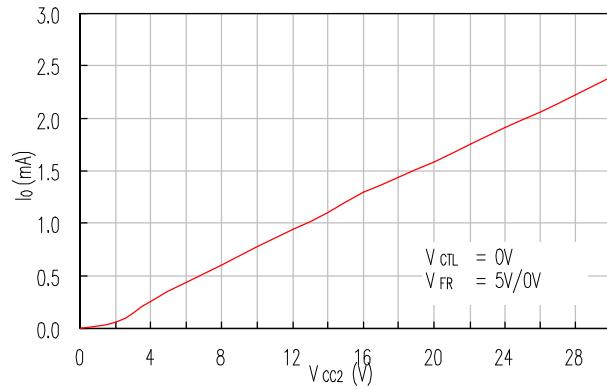
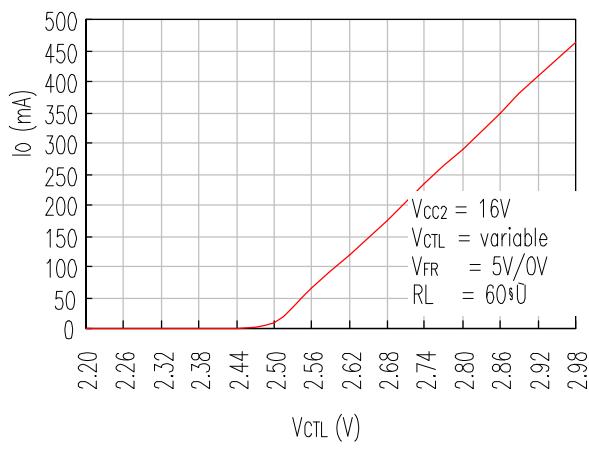
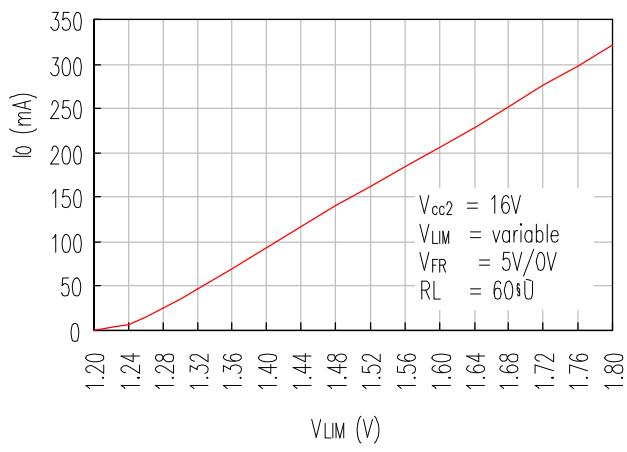


## 9. PHASE STABILIZATION

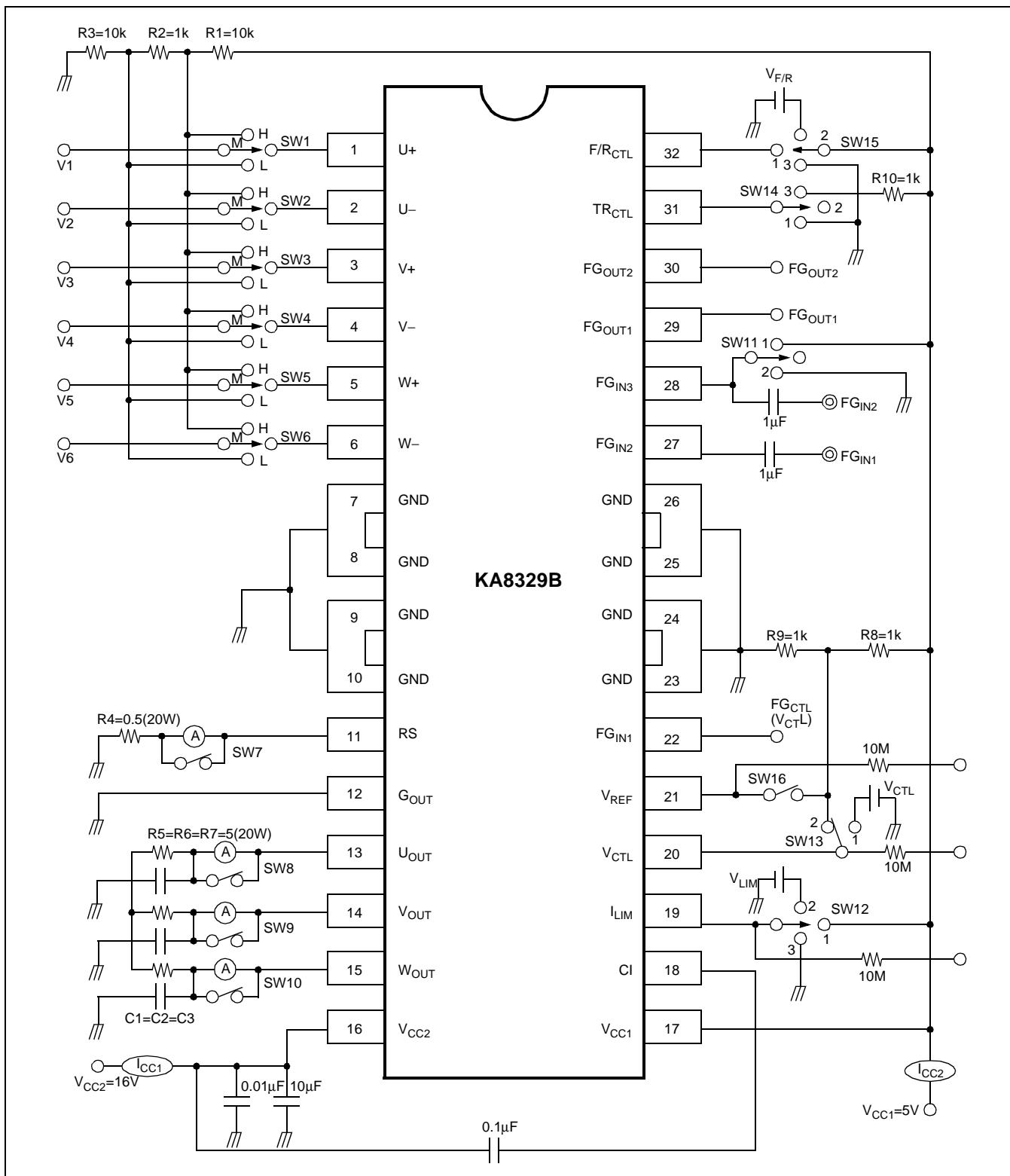


Be inserted a capacitor between pin 16 and pin 18. This capacitor, approx.  $0.1\mu F$  is for the phase stabilization of the circuit.

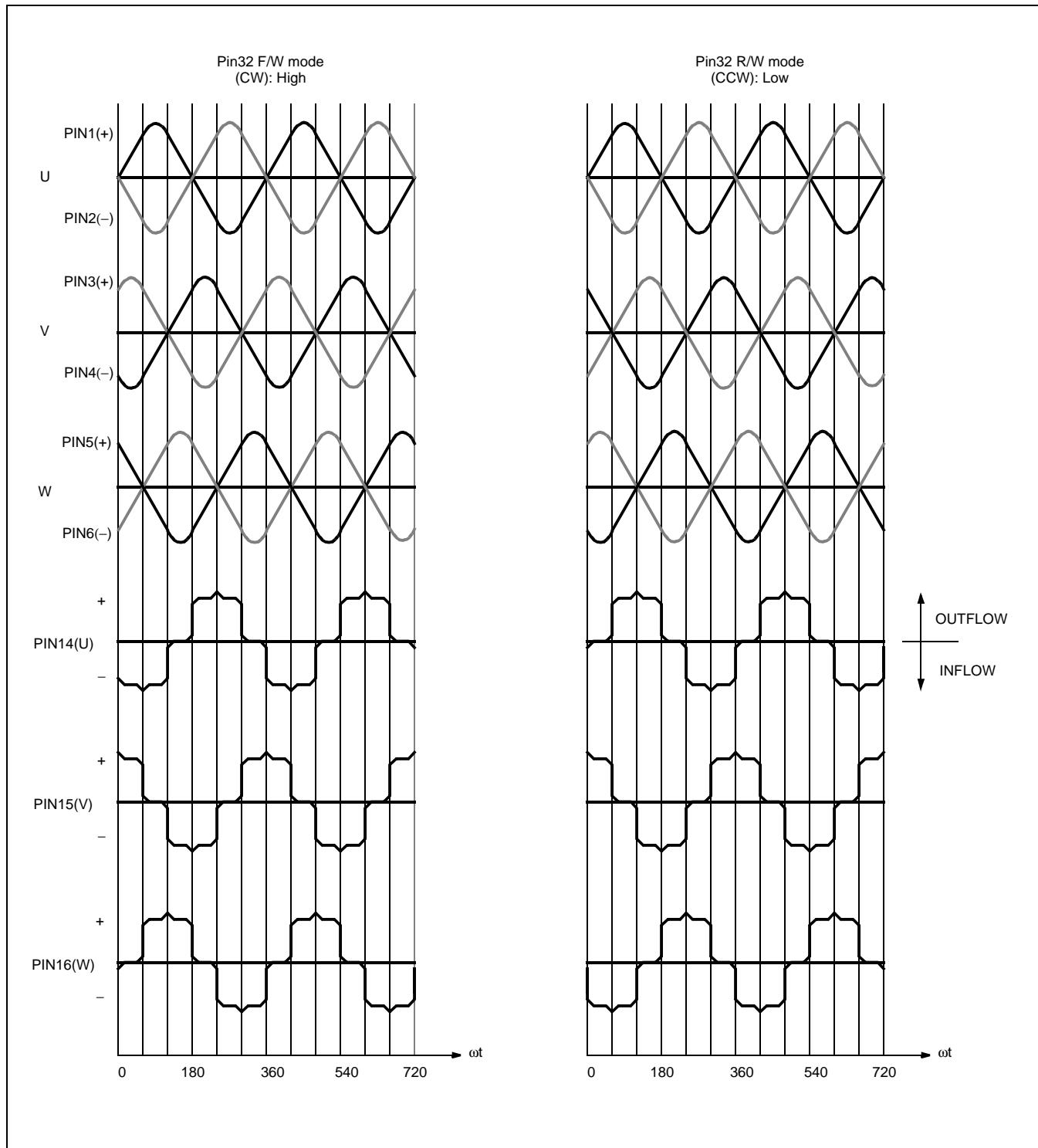
## CHARACTERISTIC GRAPHS

1.  $V_{CC1}$  vs  $I_{CC2}$ 2.  $V_{CC2}$  vs  $I_o$ 3.  $V_{CTL}$  vs  $I_o$ 4.  $V_{LIM}$  vs  $I_o$

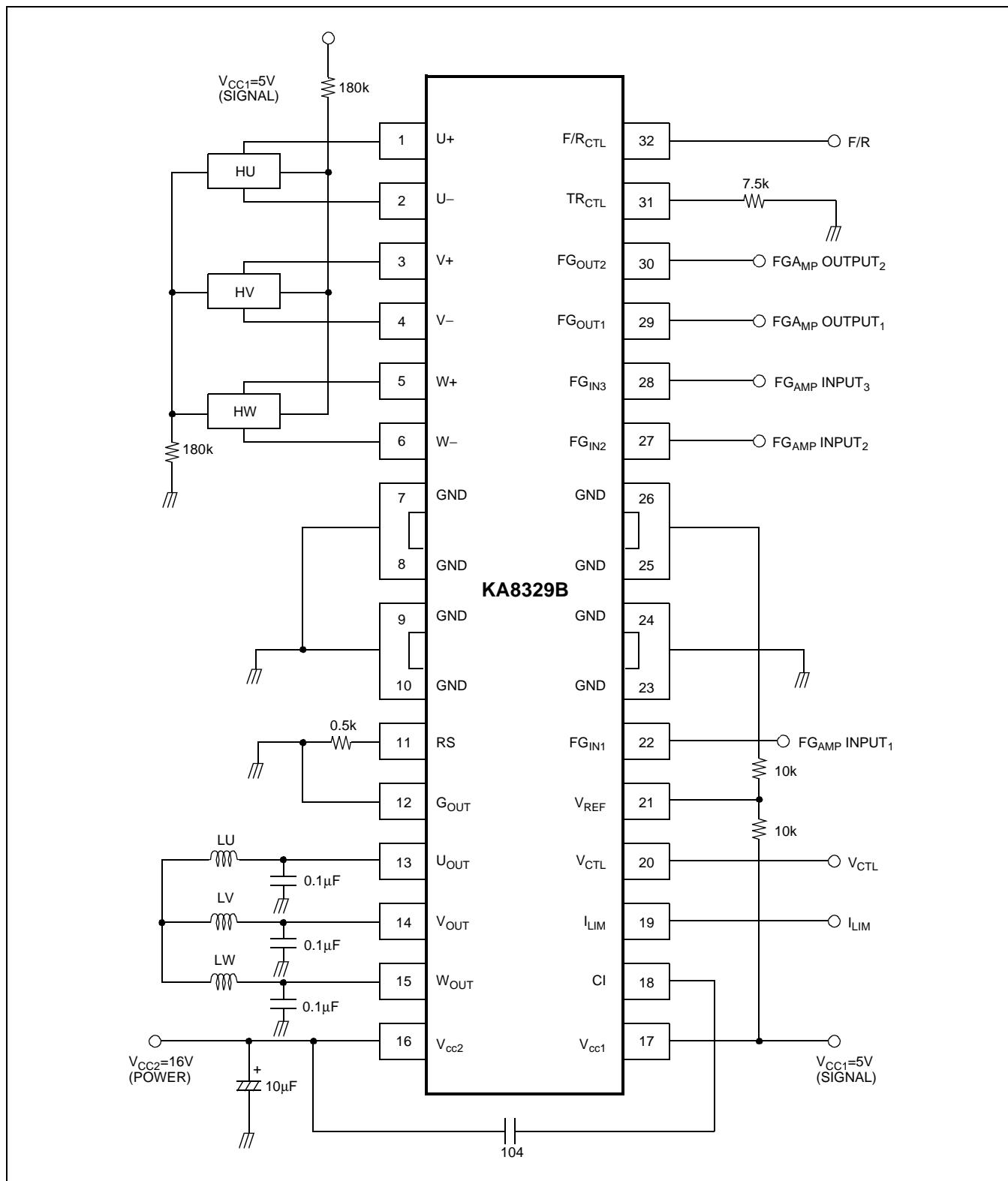
## TEST CIRCUIT



## TIMMING CHART



## APPLICATION CIRCUIT



**NOTES**

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